MAX4051AxxE Rev. A

RELIABILITY REPORT

FOR

MAX4051AxxE

PLASTIC ENCAPSULATED DEVICES

June 5, 2003

MAXIM INTEGRATED PRODUCTS

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Conclusion

The MAX4051A successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX4051A is a low-voltage, CMOS analog IC configured as an 8-channel multiplexer. This part is fully characterized for on-resistance match, on-resistance flatness, and low leakage.

This CMOS device can operate continuously with dual power supplies ranging from $\pm 2.7V$ to $\pm 8V$ or a single supply between $\pm 2.7V$ and $\pm 16V$. Each switch can handle rail-to-rail analog signals. The off leakage current is only 0.1nA at $\pm 25^{\circ}C$ or 5nA at $85^{\circ}C$

All digital inputs have 0.8V to 2.4V logic thresholds ensuring TTL/CMOS-logic compatibility when using ±5V or a single +5V supply.

B. Absolute Maximum Ratings

ltem	Rating
Voltage Referenced to GND	
V+	-0.3V to +17V
V-	+0.3V to -17V
V+ to V-	-0.3V to +17V
Voltage into Any Terminal (Note 1)	(V2V) to (V+ +2V)
	or 30mA (whichever comes first)
Continuous Current into Any Terminal	±30mA
Peak Current, NO or COM (pulsed at 1ms, 10% duty cycle)	±100mA
Storage Temp.	-65°C to +150°C
Lead Temp. (10 sec.)	+300°C
Continuous Power Dissipation (TA = $+70^{\circ}$ C)	
16-Pin PDIP	842mW
16-Pin SO	696mW
16-Pin QSOP	667mW
Derates above +70°C	
16-Pin PDIP	10.5mW/°C
16-Pin SO	8.7mW/°C
16-Pin QSOP	8.3mW/°C

Note 1: Signals on any terminal exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

II. Manufacturing Information

A. Description/Function:	Low-Voltage, CMOS Analog Multiplexer
B. Process:	SG5 - Standard 5 micron silicon gate CMOS
C. Number of Device Transistors:	161
D. Fabrication Location:	Oregon, USA
E. Assembly Location:	Korea, Thailand, Philippines or Malaysia
F. Date of Initial Production:	December, 1995

III. Packaging Information

A. Package Type:	16 Lead QSOP	16-Lead PDIP	16-Lead SO
B. Lead Frame:	Copper	Copper	Copper
C. Lead Finish:	Solder Plate	Solder Plate	Solder Plate
D. Die Attach:	Silver-filled Epoxy	Silver-filled Epoxy	Silver-filled Epoxy
E. Bondwire:	Gold (1.3 mil dia.)	Gold (1.3 mil dia.)	Gold (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler	Epoxy with silica filler	Epoxy with silica filler
G. Assembly Diagram:	# 05-0301-0759	# 05-0301-0747	# 05-0301-0748
H. Flammability Rating:	Class UL94-V0	Class UL94-V0	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112:	Level 1	Level 1	Level 1

IV. Die Information

A. Dimensions:	80 x 108 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Si (Si = 1%)
D. Backside Metallization:	None
E. Minimum Metal Width:	5 microns (as drawn)
F. Minimum Metal Spacing:	5 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

Α.	Quality Assurance Contacts:	Jim Pedicord (Manager, Reliability Operations)
		Bryan Preeshl (Executive Director)
		Kenneth Huening (Vice President)

- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{192 \text{ x } 4389 \text{ x } 400 \text{ x } 2}$ (Chi square value for MTTF upper limit) Temperature Acceleration factor assuming an activation energy of 0.8eV

 $\lambda = 2.71 \times 10^{-9}$

 λ = 2.71 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on any lot that exceeds this reliability control level. Attached Burn-In Schematic (Spec. # 06-5145) shows the static Burn-In circuit. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The AG79 die type has been found to have all pins able to withstand a transient pulse of $\pm 2000V$ per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA.

Table 1 Reliability Evaluation Test Results

MAX4051AxxE

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	: (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		400	0
Moisture Testir	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	SO PDIP QSOP	77 77 77	0 0 0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ess (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} <u>3/</u>	All V _{PS1} pins
2.	All input and output pins	All other input-output pins

TABLE II. Pin combination to be tested. 1/2/

- 1/ Table II is restated in narrative form in 3.4 below.
- $\frac{\ddot{2}}{3}$ No connects are not to be tested. $\underline{3}$ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

- 3.4 Pin combinations to be tested.
 - Each pin individually connected to terminal A with respect to the device ground pin(s) connected a. to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
 - Each pin individually connected to terminal A with respect to each different set of a combination b. of all named power supply pins (e.g., V_{SS1}, or V_{SS2} or V_{SS3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
 - Each input and each output individually connected to terminal A with respect to a combination of c. all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.









